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September 2016



FPF1504 / FPF1504L Advanced Load Management Switch

Features

- 1.0 V to 3.6 V Input Voltage Operating Range
- Typical R_{DS(ON)}:
 - 15 m Ω at V $_{\text{IN}}$ =3.3 V
 - 20 m Ω at V_{IN}=1.8 V
 - 40 m Ω at V_{IN}=1.0 V
- Slew Rate Control
- Output Discharge Function
- Low <1 µA Quiescent Current at V_{ON}=V_{IN}
- ESD Protected: 4000 V HBM, 2000 V CDM
- GPIO/CMOS-Compatible Enable Circuitry
- Active HIGH and active LOW versions

Applications

- Mobile Devices and Smart Phones
- Portable Media Devices
- Digital Cameras
- Advanced Notebook, UMPC, and MID
- Portable Medical Devices
- GPS and Navigation Equipment

Description

The FPF1504/FPF1504L are low-R_{DS} P-channel MOSFET load switches of the IntelliMAX[™] family. Integrated slew-rate control prevents excessive inrush current from the supply rails with capacitive loads common in power applications. In addition, the FPF1504/FPF1504L feature output discharge capability.

The input voltage range operates from 1.0 V to 3.6 V to fulfill today's mobile device supply requirements. Switch control is by a logic input (ON pin) capable of interfacing directly with low-voltage CMOS control signals and GPIOs in embedded processors.

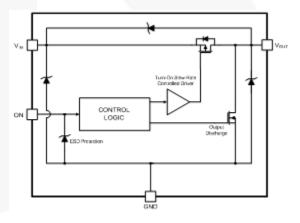
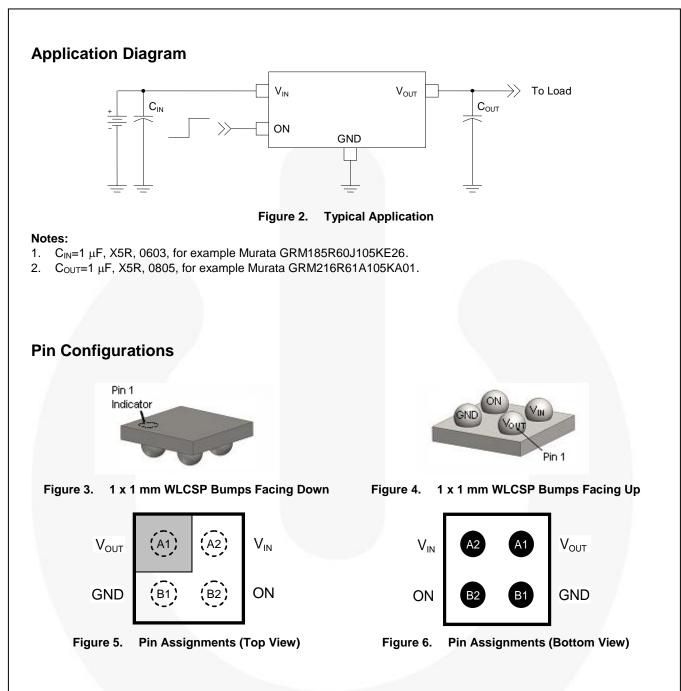


Figure 1. Block Diagram

Part Number	Top Mark	Switch (Typical) At 1.8 V _{IN}	Input Buffer	Output Discharge	ON Pin Activity	Package			
FPF1504UCX	G4	20 mΩ	CMOS	YES	Active HIGH	4-Ball, WLCSP, 0.5 mm Pitch			
FPF1504BUCX	G4	20 mΩ	CMOS	YES	Active HIGH	4-Ball, WLCSP with Backside Laminate, 0.5 mm Pitch			
FPF1504LUCX	GZ	20 mΩ	CMOS	YES	Active LOW	4-Ball, WLCSP, 0.5 mm Pitch			
FPF1504LBUCX	GZ	20 mΩ	CMOS	YES	Active LOW	4-Ball, WLCSP with Backside Laminate, 0.5 mm Pitch			

Ordering Information



Pin Definitions

Pin #	Name	Description
A1	V _{OUT}	Switch Output
A2	V _{IN}	Supply Input; Input to the Power Switch
B1	GND	Ground
B2	ON	ON/OFF Control

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Paramete	Min.	Max.	Unit		
V _{IN}	V _{IN} , V _{OUT} , V _{ON} to GND		-0.3	4.0	V	
I _{SW}	Maximum Continuous Switch Current			1.5	А	
PD	Power Dissipation at T _A =25°C			1.0	W	
T _{STG}	Storage Junction Temperature	-65	+150	°C		
T _A	Operating Temperature Range		-40	+85	°C	
	Thermal Pasistance, Junction to Ambient	1S2P with 1 Thermal Via		95	°C/W	
Θ_{JA}	Thermal Resistance, Junction-to-Ambient	1S2P without Thermal Via		187	0/11	
500	Electrostotic Discharge Canability	Human Body Model, JESD22-A114	4		- kV	
ESD	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101	2			

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{IN}	Supply Voltage	1.0	3.6	V
TA	Ambient Operating Temperature	-40	+85	°C

Symbol	Param	eter	Conditions	Min.	Тур.	Max.	Units	
Basic O	peration					1 1		
V _{IN}	Supply Voltage			1.0		3.6	V	
$I_{Q(OFF)}$	Off Supply	FPF1504	V _{ON} =GND, V _{OUT} =Open		0.25			
	Current	FPF1504L	V _{ON} = V _{IN} , V _{OUT} =Open		0.3		μA	
	Off Switch	FPF1504	V _{ON} =GND, V _{OUT} =GND		0.25			
SD(OFF)	Current	FPF1504L	V _{ON} = V _{IN} , V _{OUT} =GND		0.3			
			I _{OUT} =0 mA, V _{IN} =3.6 V, V _{ON} =V _{IN}		0.08			
	Quiescent	FPF1504	I _{OUT} =0 mA, V _{ON} =V _{IH(MIN)}		0.75			
Ι _Q	Current		I _{OUT} =0 mA, V _{IN} =3.6 V, V _{ON} =GND	1	0.08			
	1	FPF1504L	I _{OUT} =0 mA, V _{ON} =V _{IL(MAX)}		0.95			
			V _{IN} =3.3 V, I _{OUT} =200 mA, T _A =25°C	2	15	30		
			V _{IN} =1.8 V, I _{OUT} =200 mA, T _A =25°C		20	40	mΩ	
Ron	On Resistance		V _{IN} =1.5 V, I _{OUT} =200 mA, T _A =25°C		30			
			V _{IN} =1.0 V, I _{OUT} =200 mA, T _A =25°C		40	80		
			V_{IN} =1.8 V, I_{OUT} =200 mA, T_A =85°C ⁽³⁾		35	50		
R _{PD}	Output Discharge Resistance	e Pull-Down	V _{ON} =0 V or V _{IN} , I _{OUT} =-20 mA		65	95	Ω	
VIH	On Input Logic High Voltage	FPF1504		0.8			- v	
VIL	On Input Logic Low Voltage	FPF1504				0.3		
I _{ON}	On Input Leakage	e	V _{ON} =V _{IN} or GND			1	μA	
Dynamic	Characteristics		· · · ·	1				
t _{DON}	Turn-On Delay ⁽⁴⁾	FPF1504			80			
t _R	V_{OUT} Rise Time ⁽⁴⁾	FPF1504	R _L =10 Ω, C _L =0.1 μF, V _{IN} =3.3 V, $T_A=25$ °C		130		μs	
t _{ON}	Turn-On Time ⁽⁴⁾	FPF1504			210	1		
	Turn-On	FPF1504			70	100		
t _{DON}	Delay ⁽⁴⁾	FPF1504L			95			
1	Vout Rise	FPF1504	R _L =500 Ω, C _L =0.1 μF, V _{IN} =3.3 V,		110	150		
t _R	Time ⁽⁴⁾	FPF1504L	T _A =25°C		115		μs	
	Turn-On Time ⁽⁴⁾	FPF1504			180	250		
t _{ON}	Tum-On Time'	FPF1504L			210			

Electrical Characteristics (Continued)

Unless otherwise noted, V_{IN}=1.0 to 3.6 V, T_A=-40 to +85°C; typical values are at V_{IN}=3.3 V and T_A=25°C.

Symbol	Parameter		Conditions	Min.	Тур.	Max.	Units
Dynamic Characteristics (Continued)							
t _{DOFF}	Turn-Off Delay ⁽⁴⁾	FPF1504			25	30	
t _F	V _{OUT} Fall Time ⁽⁴⁾	FPF1504	$\begin{array}{l} {\sf R}_{\sf L}{=}10\;\Omega,{\sf C}_{\sf L}{=}0.1\;\mu{\sf F},{\sf V}_{\sf IN}{=}3.3\;{\sf V},\\ {\sf T}_{\sf A}{=}25^{\circ}{\sf C} \end{array}$		2		μs
t _{OFF}	Turn-Off Time ⁽⁴⁾	FPF1504			27		
	Turn-Off	FPF1504			25		
t _{DOFF}	Delay ⁽⁴⁾	FPF1504L			2		
t _F V _{OUT} Fall Time ⁽⁴⁾	(4) FPF1504	R _L =500 Ω, C _L =0.1 μF, V _{IN} =3.3 V,	6	12			
	VOUT Fall TIME'	FPF1504L	T _A =25°C		14		μs
t _{OFF} Turn-Off		FPF1504			37		
	Turn-Off Time'	FPF1504L	1		16		

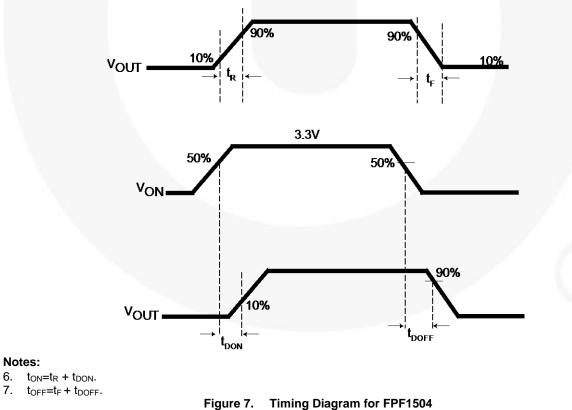
Notes:

3. This parameter is guaranteed by design and characterization; not production tested.

 $t_{DON}/t_{DOFF}/t_R/t_F$ are defined in Figure 7. 4.

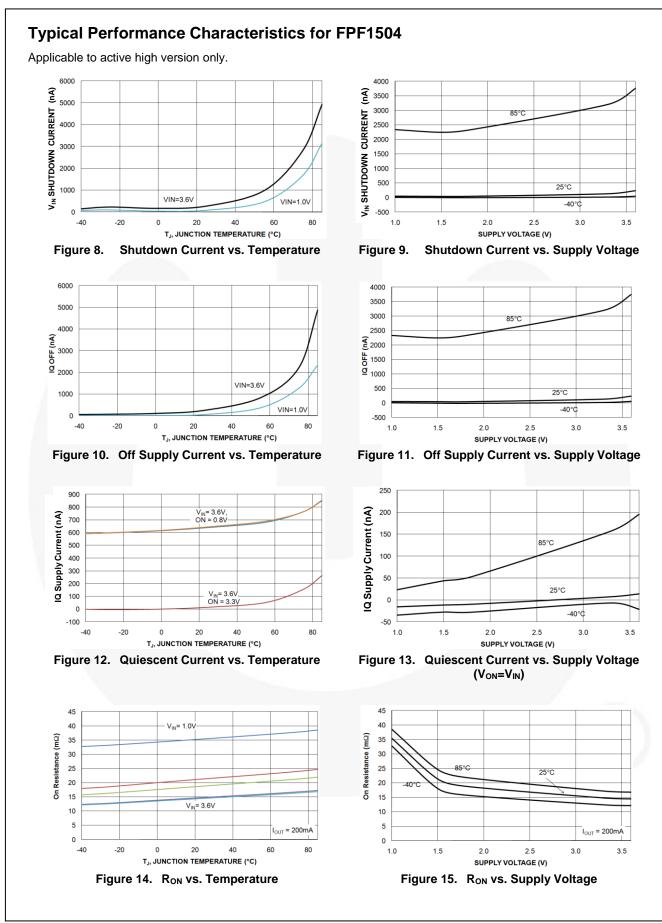
5. Output discharge path is enabled during off.

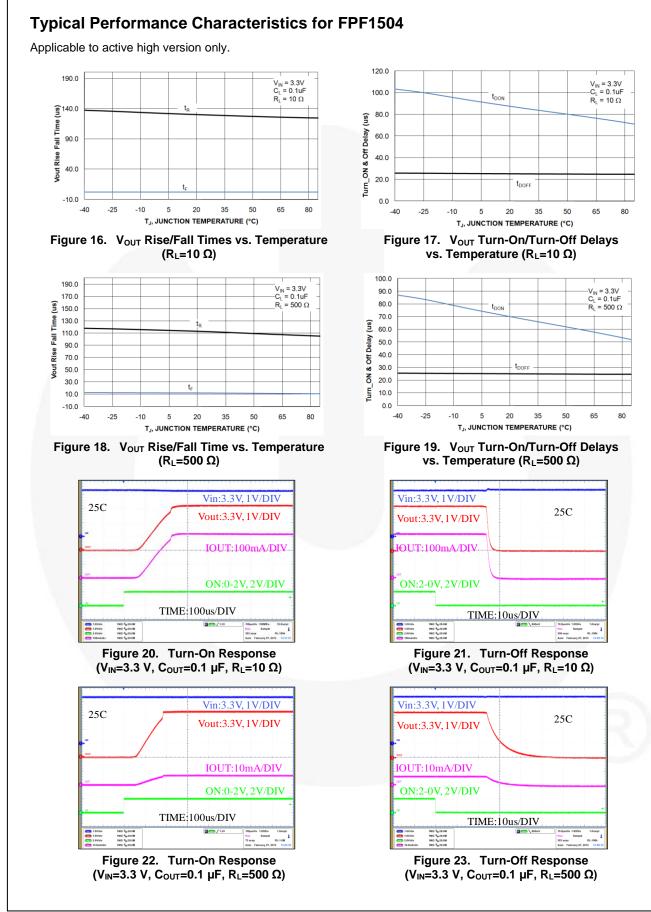
Timing Diagram – FPF1504



6.

7.





Application Information

Input Capacitor

IntelliMAXTM switches don't require an input capacitor. To reduce device inrush current, a 0.1 μ F ceramic capacitor, C_{IN}, is recommended close to the VIN pin. A higher value of C_{IN} can be used to further reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

Output Capacitor

IntelliMAXTM switches work without an output capacitor. If the applications parasitic board inductance forces V_{OUT} below GND when switching off, a 0.1 µF capacitor, C_{OUT} , should be placed between V_{OUT} and GND.

Fall Time

Device output fall time can be calculated based on RC constant of external components as follows:

$$t_{\rm F} = R_{\rm L} \times C_{\rm L} \times 2.2 \tag{1}$$

where t_F is 90% to 10% fall time, R_L is output, load and C_L is output capacitor.

Recommended Land Pattern and Layout

For best thermal performance and minimal inductance and parasitic effects, it is recommended to keep input and output traces short and the capacitors as close to The same equation works for a device with a pull-down output resistor, then R_L is replaced by a parallel connected pull-down and external output resistor combination, as follows:

$$t_{\rm F} = \frac{R_{\rm L} \times R_{\rm PD}}{R_{\rm L} + R_{\rm PD}} \times C_{\rm L} \times 2.2 \tag{2}$$

where t_F is 90% to 10% fall time, R_L is output load, R_{PD} is output pull-down resistor (65 Ω typical), and C_L is the output capacitor.

the device as possible. Below is a recommended layout for this device to achieve optimum performance.

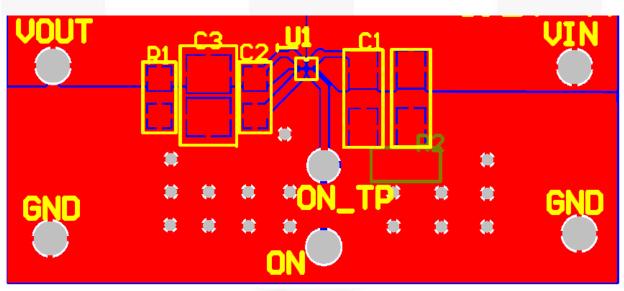
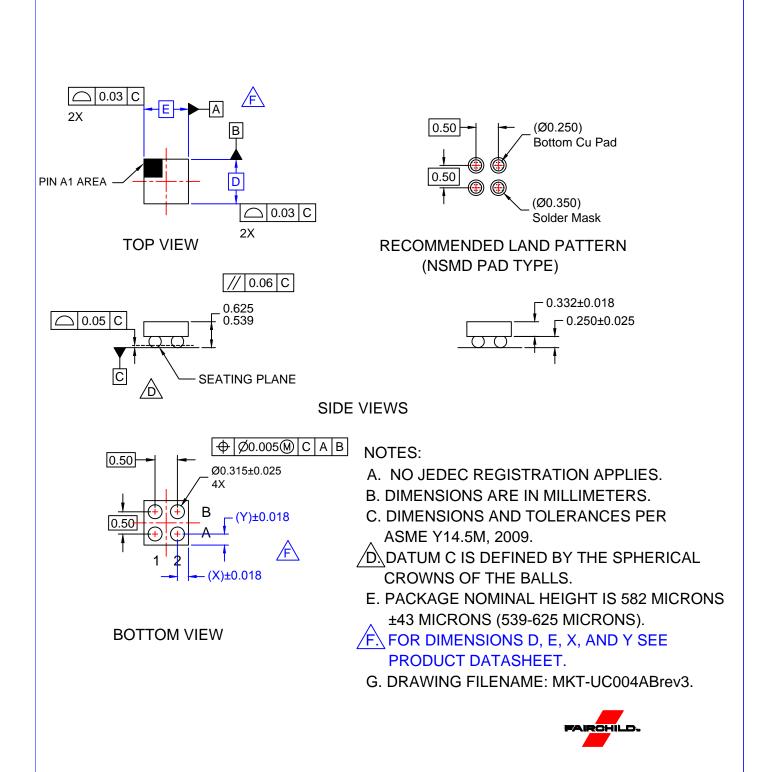


Figure 24. Recommended Land Pattern and Layout

The following information applies to the WLCSP package dimensions on the next page:

Product-Specific Dimensions

Product	D	E	Х	Y
FPF1504UCX				
FPF1504BUCX	060 um 120 um	960 μm ±30 μm	0.230 mm	0.230 mm
FPF1504LUCX	960 μm ±30 μm			
FPF1504LBUCX				



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